University of Swaziland Faculty of Science and Engineering Department of Electrical and Electronic Engineering

Supplementary Examination 2014

Title of Paper:	Analogue Design I
Course Number:	EE321
Time Allowed:	3 hrs
Instructions: 1. Au	nswer any four (4) questions.

2. Each question carries 25 marks.

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This paper contains eighty (8) pages including this page.

- a) Write some notes on the advantages of tuned amplifiers.
- b) For the low pass filter in Fig. 1(b), $C_F = 0.01 \mu F$, $R_F = 10k\Omega$ and $R_i = 1k\Omega$. Calculate the voltage gain at 1MHz. [10]



c) Derive an expression for the voltage gain for the circuit in Fig. 1(c). Assume both transistors are well matched and R_E is very large.



[2]



d) A compensating capacitor of 1000 pF has a maximum charging current of 1mA. What is the slew rate? [2]

2

e) Define f_T .

a) For the two-power supply version of the voltage-divider bias circuit shown in Fig. 2(a) derive an expression for the emitter current I_E in terms of β . [3]



Fig. 2(a)

b) For Fig. 2(b) below, use the following parameters: $R_B = 330k\Omega$, $R_L = 5k\Omega$, $R_{sig} = 5k\Omega$, $I_C = 1.3mA$, $V_T = 25mV$ and $\beta = 100$.



Fig. 2(b)

- i) Draw the small signal model of the circuit.
- ii) Calculate the value of R_c so that the overall gain, $G_v = \frac{v_o}{v_{sig}} = -27V/V$. [8]
- c) What is the frequency of oscillation of the astable multivibrator circuit shown in Fig. 2(c) below, where $V_{CC} = +5V$, $-V_{EE} = -5V$, $R_1 = 6.8k\Omega$, $R_2 = 6.8k\Omega$, $R = 10k\Omega$ and $C = 0.001 \mu F$. [6]



d) An amplifier has an input power of 2mW and an output power of 345mW. What is its decibel power gain? [2]

4

e) Differentiate between an ideal and non-ideal op amp.

[4]

a) Consider the emitter-follower amplifier of Fig. 3(a) for I = 1mA, $\beta = 100$, $V_T = 25mV$, $R_B = 100k\Omega$, $R_{sig} = 20k\Omega$ and $R_L = 1k\Omega$.



Fig. 3(a)

- i) Find R_{in} [5] [5]
- ii) Find $\frac{v_o}{v_{sig}}$
- b) A parallel resonant circuit has a capacitor of 100 pF in one branch and inductance of $100 \mu H$ plus a resistance of 10Ω in the parallel branch. If the supply voltage is 10V, calculate:

i) The resonant frequency	[3]
ii) The impedance of the circuit	[3]
iii) The line current at resonance	[3]
iv) The Q-factor of the circuit.	[3]

c) A particular small geometry BJT has $f_T = 5GHz$ and $C_{\mu} = 0.1 pF$ when operated at $I_c = 0.5 mA$ and $V_T = 25 mV$.

i) Find g_m	[1]
ii) When $\beta = 150$, find r_{α} and f_{α} .	[2]

a) Consider the common-emitter amplifier shown in Fig. 4(a) under the following conditions: $R_{sig} = 5k\Omega$, $R_1 = 33k\Omega$, $R_2 = 22k\Omega$, $R_E = 3.9k\Omega$, $R_C = 4.7k\Omega$, $R_L = 5.6k\Omega$, $V_{cc} = 5V$, $r_o = 300k\Omega$, $\beta = 120$, dc collector current, $I_C = 0.3mA$, $V_T = 25mV$, $C_{\mu} = 1pF$, $f_T = 700MHz$ and $r_x = 50\Omega$. Find:

[4]

[10]

[4]

[3] [2]

[2]

- i) C_{π}
- ii) The upper 3-dB frequency, f_H .





- b) Determine the output voltage of an op amp for input voltages of $V_{i_1} = 150 \mu V$ and $V_{i_2} = 140 \mu V$. The amplifier has a differential gain of $A_d = 4000$ and the value of Common-Mode Rejection Ratio (CMRR) is 10^5 .
- c) In Fig. 4(c) below, V_{sat} = ±13V, R₁ = 1kΩ and R₂ = 100kΩ. Calculate:
 i) The upper threshold point (UTP)
 ii) The lower threshold point LTP
 iii) The hysteresis voltage (V_H)



a) The input Miller capacitance in Fig. 5(a) below creates a bypass circuit on the input side. If A = 300 and C = 10 pF, what is the critical frequency of this bypass circuit? [5]





b) For Fig. 5(b) below, determine f_{L_s} , i.e. low frequency response due to the input coupling capacitor, C_s . $V_T = 26mV$ and $V_{BE} = 0.7V$. [10]



c) For the noninverting amplifier in Fig. 5(c) derive an expression its open loop gain, $A_{v} = \frac{V_{out}}{V_{v}}.$ [6]



[4]

